

MITSUBISHI THYRISTOR MODULES  
**TM25RZ/EZ-M,-H**

MEDIUM POWER GENERAL USE  
 INSULATED TYPE

TM25RZ/EZ-M,-H



- **IT (AV)** Average on-state current ..... **25A**
- **IF (AV)** Average forward current ..... **25A**
- **VRRM** Repetitive peak reverse voltage  
 ..... **400/800V**
- **VDRM** Repetitive peak off-state voltage  
 ..... **400/800V**
- **MIX DOUBLE ARMS**
- **Insulated Type**
- **UL Recognized**

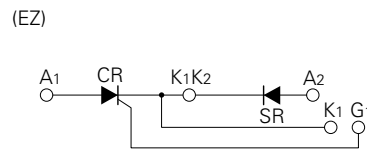
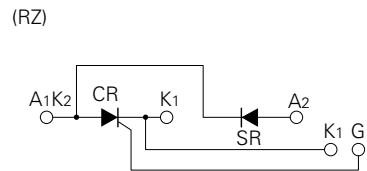
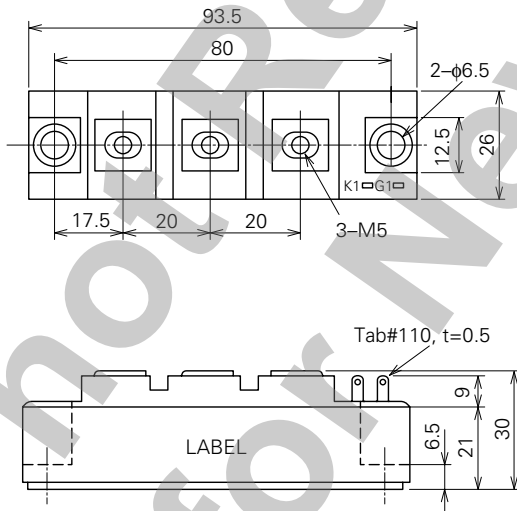
Yellow Card No. E80276 (N)  
 File No. E80271

**APPLICATION**

DC motor control, NC equipment, AC motor control, contactless switches,  
 electric furnace temperature control, light dimmers

**OUTLINE DRAWING & CIRCUIT DIAGRAM**

Dimensions in mm



## TM25RZ/EZ-M,-H

MEDIUM POWER GENERAL USE

INSULATED TYPE

## ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Voltage class		Unit
		M	H	
VRRM	Repetitive peak reverse voltage	400	800	V
VRSM	Non-repetitive peak reverse voltage	480	960	V
VR (DC)	DC reverse voltage	320	640	V
VDRM	Repetitive peak off-state voltage	400	800	V
VDSM	Non-repetitive peak off-state voltage	480	960	V
VD (DC)	DC off-state voltage	320	640	V

Symbol	Parameter	Conditions	Rated Values	Unit
$I_T$ (RMS), $I_F$ (RMS)	RMS current		39	A
$I_T$ (AV), $I_F$ (AV)	Average current	Single-phase, half-wave 180° conduction, $T_c=93^\circ\text{C}$	25	A
$I_{TSM}$ , $I_{FSM}$	Surge (non-repetitive) current	One half cycle at 60Hz, peak value	500	A
$I^2t$	$I^2t$ for fusing	Value for one cycle of surge current	$1.0 \times 10^3$	$\text{A}^2\text{s}$
$di/dt$	Critical rate of rise of on-state current	$V_D=1/2V_{DRM}$ , $I_G=0.5\text{A}$ , $T_j=125^\circ\text{C}$	100	$\text{A}/\mu\text{s}$
PGM	Peak gate power dissipation		5.0	W
PG (AV)	Average gate power dissipation		0.5	W
VFGM	Peak gate forward voltage		10	V
VRGM	Peak gate reverse voltage		5.0	V
IFGM	Peak gate forward current		2.0	A
$T_j$	Junction temperature		-40~125	$^\circ\text{C}$
$T_{stg}$	Storage temperature		-40~125	$^\circ\text{C}$
$V_{iso}$	Isolation voltage	Charged part to case	2500	V
—	Mounting torque	Main terminal screw M5	1.47~1.96	N·m
			15~20	kg·cm
		Mounting screw M6	1.96~2.94	N·m
			20~30	kg·cm
—	Weight	Typical value	160	g

## ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
IRRM	Repetitive peak reverse current	$T_j=125^\circ\text{C}$ , $V_{RRM}$ applied	—	—	4.0	mA
IDRM	Repetitive peak off-state current	$T_j=125^\circ\text{C}$ , $V_{DRM}$ applied	—	—	4.0	mA
$V_{TM}$ , $V_{FM}$	Forward voltage	$T_j=125^\circ\text{C}$ , $I_{TM}=I_{FM}=75\text{A}$ , instantaneous meas.	—	—	1.5	V
$dv/dt$	Critical rate of rise of off-state voltage	$T_j=125^\circ\text{C}$ , $V_D=2/3V_{DRM}$	500	—	—	$\text{V}/\mu\text{s}$
VGT	Gate trigger voltage	$T_j=25^\circ\text{C}$ , $V_D=6\text{V}$ , $R_L=2\Omega$	—	—	3.0	V
VGD	Gate non-trigger voltage	$T_j=125^\circ\text{C}$ , $V_D=1/2V_{DRM}$	0.25	—	—	V
IGT	Gate trigger current	$T_j=25^\circ\text{C}$ , $V_D=6\text{V}$ , $R_L=2\Omega$	10	—	50	mA
$R_{th(j-c)}$	Thermal resistance	Junction to case (per 1/2 module)	—	—	0.8	$^\circ\text{C}/\text{W}$
$R_{th(c-f)}$	Contact thermal resistance	Case to fin, conductive grease applied (per 1/2 module)	—	—	0.2	$^\circ\text{C}/\text{W}$
—	Insulation resistance	Measured with a 500V megohmmeter between main terminal and case	10	—	—	$\text{M}\Omega$

Note: Items of the above table applies to the Thyristor part and the Diode part as circled in the following tables.

# TM25RZ/EZ-M,-H

MEDIUM POWER GENERAL USE  
INSULATED TYPE

## MAXIMUM RATINGS

Item	VRRM	VRSM	VR (DC)	VDRM	VD SM	VD (DC)	IT (RMS)	IT (AV)	ITSM	$i^2t$	di/dt
							IF (RMS)	IF (AV)	IFSM		
Thyristor	○	○	○	○	○	○	○	○	○	○	○
Diode	○	○	○	—	—	—	○	○	○	○	—

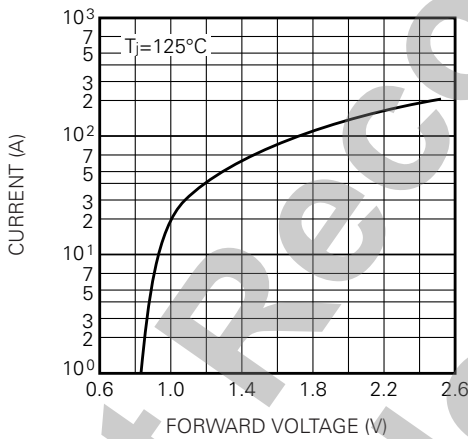
Item	PGM	PG (AV)	VFGM	IFGM	Tj	Tstg
Thyristor	○	○	○	○	○	○
Diode	—	—	—	—	○	○

## ELECTRICAL CHARACTERISTICS

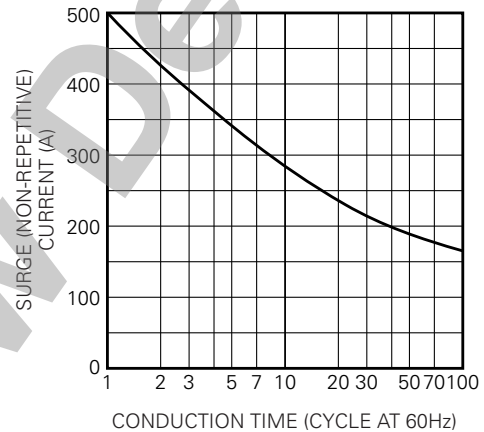
Item	IRRM	IDRM	VTM	dv/dt	VGT	VGD	IGT	Rth (j-c)	Rth (c-f)
			VFM						
Thyristor	○	○	○	○	○	○	○	○	○
Diode	○	—	○	—	—	—	—	○	○

## PERFORMANCE CURVES

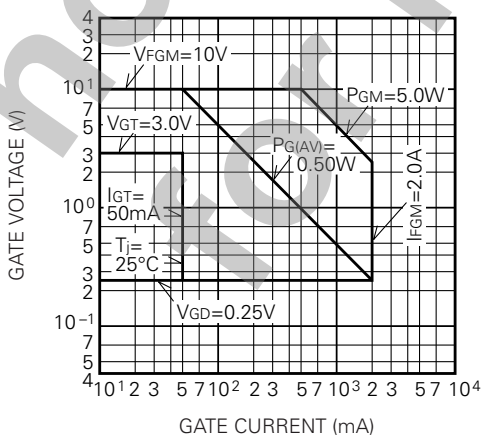
MAXIMUM FORWARD CHARACTERISTIC



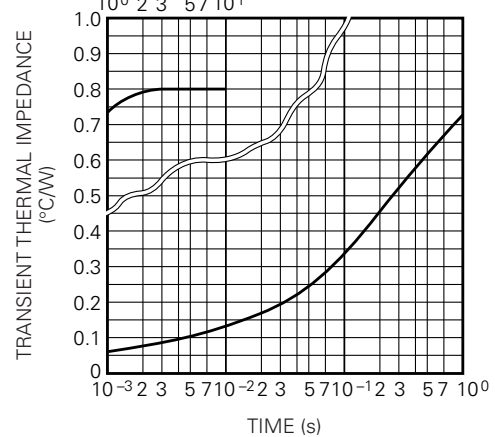
RATED SURGE (NON-REPETITIVE) CURRENT



GATE CHARACTERISTICS

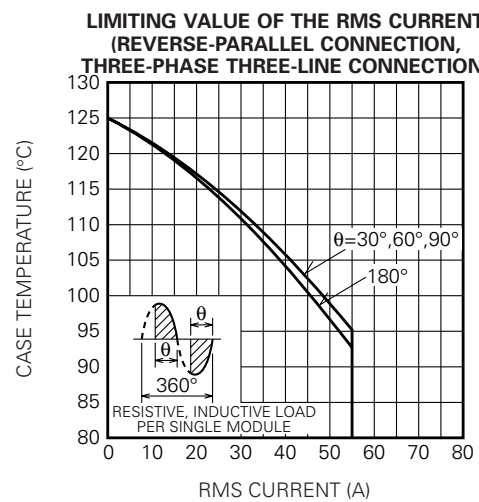
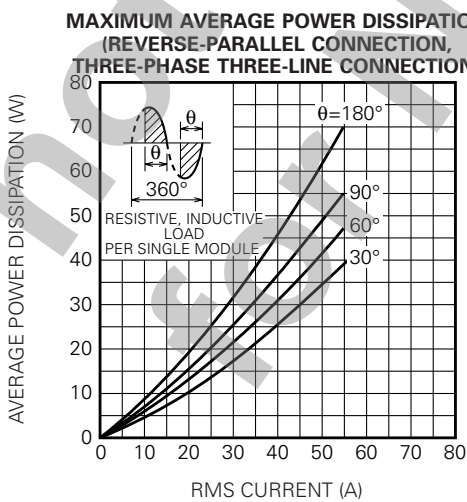
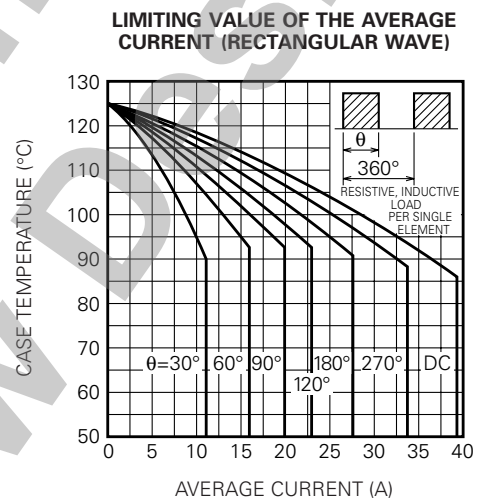
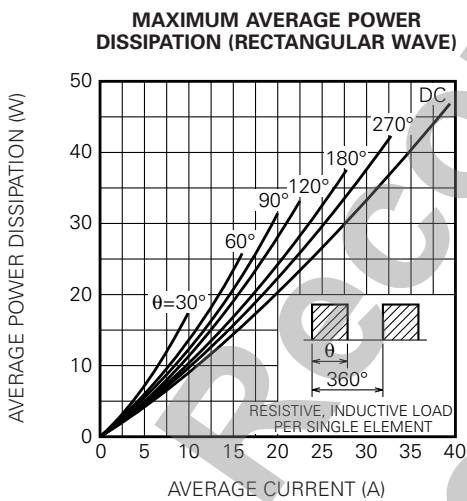
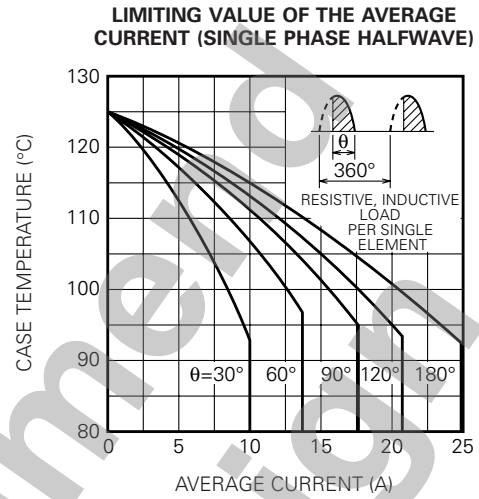
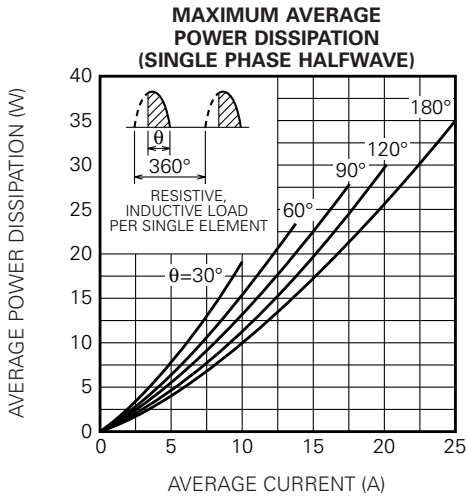


MAXIMUM TRANSIENT THERMAL IMPEDANCE (JUNCTION TO CASE)



TM25RZ/EZ-M,-H

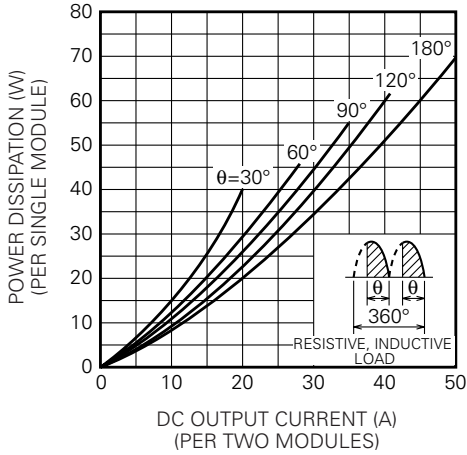
MEDIUM POWER GENERAL USE  
INSULATED TYPE



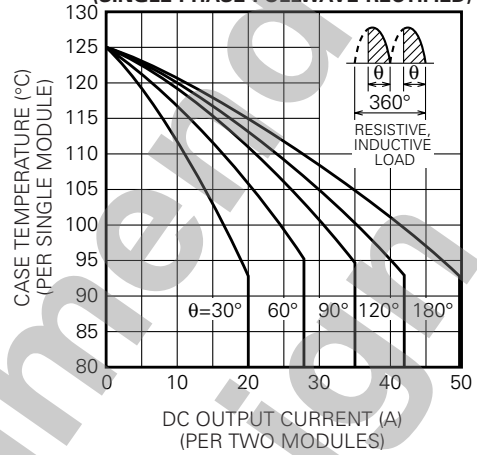
TM25RZ/EZ-M,-H

MEDIUM POWER GENERAL USE  
INSULATED TYPE

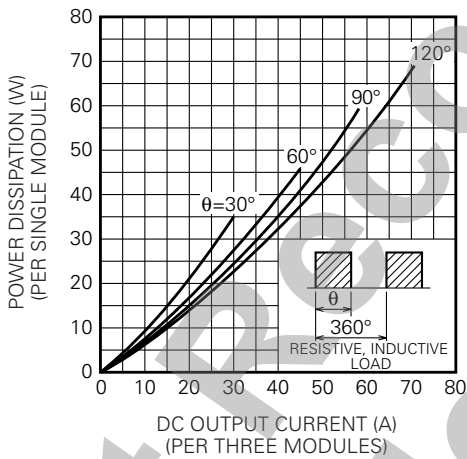
MAXIMUM POWER DISSIPATION  
(SINGLE PHASE FULLWAVE RECTIFIED)



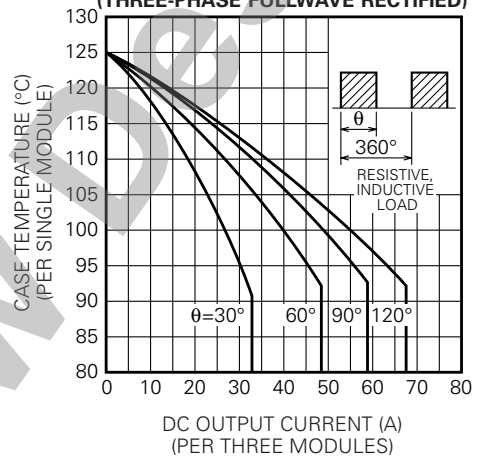
LIMITING VALUE OF THE DC OUTPUT CURRENT  
(SINGLE PHASE FULLWAVE RECTIFIED)



MAXIMUM POWER DISSIPATION  
(THREE-PHASE FULLWAVE RECTIFIED)



LIMITING VALUE OF THE DC OUTPUT CURRENT  
(THREE-PHASE FULLWAVE RECTIFIED)



not for New